TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC7WH157FU, TC7WH157FK

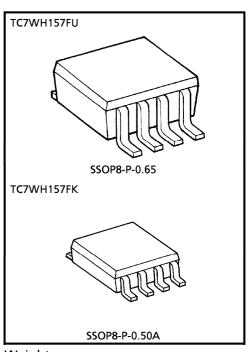
2-CHANNEL MULTIPLEXER

The TC7WH157 is an advanced high speed CMOS 2-CHANNEL MULTIPLEXER fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. It consists of 2-input digital multiplexers with common select and strobe inputs.

When the STROBE input is held "H" level, selection of data is inhibited and all the outputs become "L" level. The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs. An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and on two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

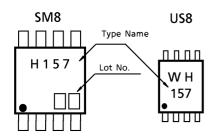
FEATURES

- High Speed $\cdots t_{pd} = 4.1 \text{ns}$ (Typ.) at
 - $V_{CC} = 5V$
- Low Power Dissipation $I_{CC} = 4\mu A$ (Max.) at
 - Ta = 25°C
- High Noise Immunity $\cdots \cdots \vee V_{NIH} = V_{NIL} = 28\%$ V_{CC} (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays ····· t_{pLH}=t_{pHL}
- Wide Operating Voltage Range… V_{CC} (opr) = 2~5.5V

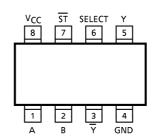


Weight SSOP8-P-0.65 : 0.02g (Typ.) SSOP8-P-0.50A : 0.01g (Typ.)

MARKING



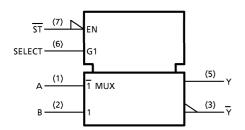
PIN ASSIGNMENT (TOP VIEW)



MAXIMUM RATINGS (Ta = 25° C)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage Range	Vcc	-0.5~7.0	V	
DC Input Voltage	VIN	-0.5~7.0	٧	
DC Output Voltage	Vout	-0.5~V _{CC} +0.5	٧	
Input Diode Current	IK	- 20	mA	
Output Diode Current	^I ОК	± 20	mA	
DC Output Current	IOUT	± 25	mA	
DC V _{CC} /Ground Current	lcc	± 50	mA	
Dawar Dissination	D-	300 (SM8)	mW	
Power Dissipation	PD	200 (US8)	i iiivv	
Storage Temperature	T _{stg}	-65~150	°C	
Lead Temperature (10 s)	TL	260	°C	

LOGIC DIAGRAM



TRUTH TABLE

	INP	OUT	PUTS		
ST	SELECT	Α	В	Υ	Ÿ
Н	×	×	×	L	Н
L	L	L	×	L	Н
L	L	Н	×	Н	L
L	Н	×	L	L	Н
L	Н	×	Н	Н	L

x : Don't care

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	Vcc	2.0~5.5	V
Input Voltage	VIN	0~5.5	<
Output Voltage	Vout	0~V _{CC}	٧
Operating Temperature	T _{opr}	- 40∼8 5	°C
Input Rise and Fall Time	dt / dv	$0 \sim 100 \text{ (V}_{CC} = 3.3 \pm 0.3 \text{V)}$	ns / V
input Rise and Fail Time	at/av	$0\sim20 \ (V_{CC} = 5 \pm 0.5V)$	115 / V

DC ELECTRICAL CHARACTERISTICS

CHADACTERISTIC	CTERISTIC SYMBOL TEST CONDITION		V _C C (V)	Ta = 25°C		Ta = -4	UNIT				
CHARACTERISTIC	STIVIBUL	1231 C	1E31 CONDITION		MIN.	TYP.	MAX.	MIN.	MAX.	UNIT	
High-Level				2.0	1.50	_	_	1.50			
Input Voltage	V _{IH}		_	3.0~ 5.5	V _C C ×0.7		_	V _C C × 0.7		V	
Low-Level				2.0	_	_	0.50	_	0.50		
Input Voltage	V _{IL}		$- \frac{1}{10H} = -50\mu A = \frac{2}{2}$ $\frac{1}{10H} = -4mA = \frac{3}{2}$ $\frac{1}{10H} = -8mA = \frac{2}{2}$ $\frac{1}{10L} = 50\mu A = \frac{3}{2}$	3.0~ 5.5	_		V _C C × 0.3	_	V _{CC} ×0.3	V	
				2.0	1.9	2.0	_	1.9	_		
High-Level	Voн	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -50\mu A$	3.0	2.9	3.0	_	2.9		V	
Output Voltage				4.5	4.4	4.5	_	4.4			
Toutput Voltage			$I_{OH} = -4mA$	3.0	2.58	1	_	2.48	1		
			$I_{OH} = -8mA$	4.5	3.94		_	3.80			
		$V_{IN} = V_{IH}$ $I_{OL} = 50 \mu A$ $I_{OL} = 4mA$ $I_{OL} = 8mA$	I _{OL} = 50μA	2.0		0.0	0.1	_	0.1	V	
Low-Level				3.0		0.0	0.1	_	0.1		
Output Voltage	VOL			4.5		0.0	0.1	_	0.1		
Cutput Voltage			$I_{OL} = 4mA$	3.0			0.36	_	0.44		
			$I_{OL} = 8mA$	4.5	_	_	0.36	_	0.44		
Input Leakage Current	IIN	V _{IN} = 5.5V or GND		0~ 5.5		1	± 0.1	_	± 1.0	μ A	
Quiescent Supply Current	lcc	V _{IN} = V _{CC} o	V _{IN} = V _{CC} or GND		_	_	2.0	_	20.0	μ A	

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f$
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CHARACTERISTIC	CVMPOL	YMBOL TEST CONDITION VCC (V		ONDITION		Ta = 25°C			Ta = -40~85°C		
CHARACTERISTIC	STIVIBUL			V _{CC} (V) C _L (pF) M	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT	
Prepagation Dalou	I Topagation Belay tall		3.3 ± 0.3	15		6.2	9.7	1.0	11.5		
Time		3.3 ± 0.3	50	_	8.7	13.2	1.0	15.0	nc		
(A, B-Y)	tpHL		5.0 ± 0.5	15		4.1	6.4	1.0	7.5	ns	
(A, B-1)		3.0 ± 0.3	50		5.6	8.4	1.0	9.5			
Propagation Delay Time tpLH tpHL	3.3 ± 0.3	15		8.4	13.2	1.0	15.5				
	tpLH	· .	3.3 ± 0.3	50	_	10.9	16.7	1.0	19.0	nc	
	tpHL		5.0 ± 0.5	15	_	5.3	8.1	1.0	9.5	ns	
(SEEECI-1)	(SELECT-Y)			50	_	6.8	10.1	1.0	11.5		
Drangation Dalou			3.3 ± 0.3	15		8.7	13.6	1.0	16.0		
Propagation Delay Time	tpLH		3.5 ± 0.5	50	_	11.2	17.1	1.0	19.5	nc	
(ST-Y)	tpHL		5.0 ± 0.5	15	_	5.6	8.6	1.0	10.0	ns	
(31-1)		'		50	_	7.1	10.6	1.0	12.0		
Input Capacitance	CIN			·		4	10	_	10	рF	
Power Dissipation Capacitance	C _{PD}	(Note 1)				20	_	_		pF	

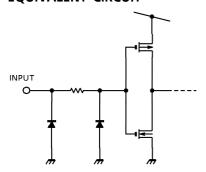
(Note 1): CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation :

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

NOISE CHARACTERISTICS (Ta = 25°C, Input $t_r = t_f = 3ns$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	V _{CC} (V)	TYP.	IMIT	UNIT
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	C _L = 50pF	5.0	0.3	0.8	٧
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	C _L = 50pF	5.0	-0.3	-0.8	٧
Minimum High Level Dynamic Input Voltage	V _{IHD}	C _L = 50pF	5.0	_	3.5	V
Maximum Low Level Dynamic Input Voltage	V _{ILD}	C _L = 50pF	5.0	1	1.5	V

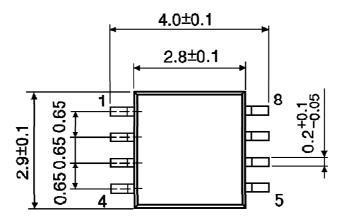
INPUT EQUIVALENT CIRCUIT

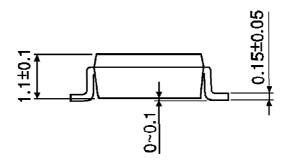


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PACKAGE DIMENSIONS

SSOP8-P-0.65 Unit: mm

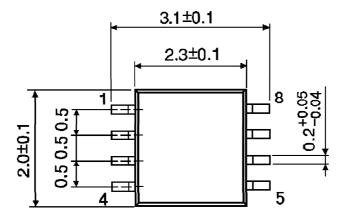


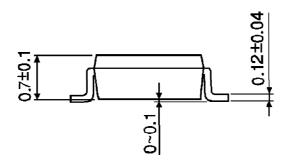


Weight: 0.02g (Typ.)

PACKAGE DIMENSIONS

SSOP8-P-0.50A Unit: mm





Weight: 0.01g (Typ.)

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